

MBR340S

Technical Data Data Sheet N0028, Rev. B

RoHS HF

MBR340S SCHOTTKY RECTIFIER



Circuit Diagram



Features

- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- Terminals finish: 100% Pure Tin
 This is a Malassa Face Paris.
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	40	v
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @Tc=80°C, rectangular wave form	3	А
Peak One Cycle Non-Repetitive Surge Current	IFSM	8.3ms, Half Sine pulse, Tc=25°C	75	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V _{F1}	@ 3A, Pulse, T _J = 25 °C	0.40	0.63	V
	V _{F2}	@ 3A, Pulse, T _J = 125 °C	0.33	0.57	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.03	1.0	mA
	R2	@V _R = rated V _R T _J = 100℃	3	20	mA
Junction Capacitance	C	@Vr = 5.0 V, Tc=25°C fsig = 1MHz	130	200	pF

* Pulse width < 300 µs, duty cycle < 2%</p>

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com -



Technical Data Data Sheet N0028, Rev. B

MBR340S

RoHS HF

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	Tstg	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	Reuc	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	Reja		70	°C/W
Approximate Weight	wt	-	0.08	g

Ratings and Characteristics Curves





Fig.2-Typical Reverse Characteristics



Fig.3-Typical Instantaneous Forward Voltage Characteristics

http://www.smc-diodes.com - sales@ smc-diodes.com •



MBR340S

RoHS HF

Technical Data Data Sheet N0028, Rev. B

Mechanical Dimensions TO-277B



SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
A	0.95	1.25	0.037	0.049	
A1	0.20	0.30	0.008	0.012	
b	0.85	0.95	0.033	0.037	
b1	1.70	1.90	0.067	0.075	
D	3.88	4.08	0.153	0.161	
D1	2.90	3.20	0.114	0.126	
D2	4.25	-	0.167	-	
е	1.74	1.94	0.069	0.076	
E	6.30	6.70	0.248	0.264	
E1	5.28	5.48	0.208	0.216	
E2	3.40	3.70	0.134	0.146	
E3	4.20	4.60	0.165	0.181	
L	0.65	1.05	0.025	0.041	
w	0.25	0.55	0.010	0.022	

Ordering Information

Device	Package	Shipping
MBR340S	TO-277B(Pb-Free)	5000pcs/ reel
MBR340STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Carrier Tape Specification TO-277B



Marking Diagram



Where XXXXX is YYWWL

3

40

s

ΥY

L

ww

= Forward Current (3A)

- = Reverse Voltage (40V)
 - = Package type
 - = Year

= Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

SYMBOL	Millimeters		
STMDUL	Min.	Max.	
A	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
P	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

China - Germany - Korea - Singapore - United States http://www.smc-diodes.com - sales@ smc-diodes.com -



Technical Data Data Sheet N0028, Rev. B

MBR340S

RoHS HF

DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions. 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC

Diode Solutions. 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..